

# HMC680LP4 / 680LP4E

v03.0609



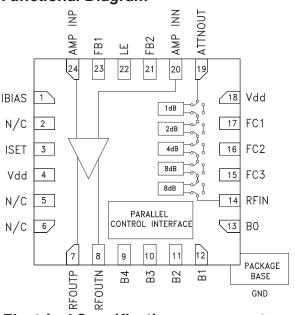
# BICMOS MMIC 5-BIT DIGITAL VARIABLE GAIN AMPLIFIER, 30 - 400 MHz

#### Typical Applications

The HMC680LP4(E) is ideal for:

- Cellular/3G Infrastructure
- WiBro / WiMAX / 4G
- Microwave Radio & VSAT
- Test Equipment and Sensors
- IF & RF Applications

#### **Functional Diagram**



#### **Features**

TTL/CMOS compatible parallel or latched parallel control interface

High Output IP3: +40 dBm (At all gain settings)

Low Noise Figure: 5 dB

Wide Gain Control Range: 23 dB

24 Lead 4x4 mm SMT Package: 16 mm<sup>2</sup> Excellent State & Step Accuracy (±0.05 dB)

#### **General Description**

The HMC680LP4(E) is a digitally controlled variable gain amplifier which operates from 30 to 400 MHz, and can be programmed to provide -4 dB to +19 dB of gain, in 1 dB steps. The HMC680LP4(E) delivers noise figure of 5 dB in its maximum gain state, with output IP3 of up to +40 dBm in any state. This high linearity DVGA also provides a differential RF output which can be used to interface directly with SAW filters in Tx and Rx applications, and with digital to analog converters in Rx chains. The HMC680LP4(E) is housed in a RoHS compliant 4x4 mm QFN leadless package, and is CMOS/TTL compatible.

### Electrical Specifications, $T_A = +25^{\circ}$ C, 50 Ohm System, Vdd = +5V

Parameter			Тур.	Max.	Units
Frequency Range		30 - 400			MHz
Gain (Maximum Gain State)		17	19		dB
Gain Control Range			23		dB
Input Return Loss			12		dB
Output Return Loss			13		dB
Gain Accuracy: (Referenced to Maximum Gain S	State) All Gain States	± (0.15 + 3% of Gain Setting) Max.		dB	
Output Power for 1dB Compression		23	25		dBm
Output Third Order Intercept Point (Two-Tone O	utput Power= +5 dBm Each Tone) [1]		40		dBm
Output Second Order Intercept Point (Two-Tone	Output Power= +5 dBm Each Tone) [1]		65		dBm
Harmonics 2nd Order 3rd Order			70 75		dBc dBc
Step Accuracy (Referenced to Maximum Gain State)			±0.2		dB
Noise Figure (max gain state)			5		dB
Switching Characteristics tRise, tFall (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)			11 13		ns ns
Control Supply Current Idd			4	5	mA
Amp Supply Current (RFOUTP)			122	135	mA
Amp Supply Current (RFOUTN)			122	135	mA
FAT 11 FOAMI					

[1] Test frequency 50 MHz

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# **HMC680\* PRODUCT PAGE QUICK LINKS**

Last Content Update: 02/23/2017

### COMPARABLE PARTS -

View a parametric search of comparable parts.

### **EVALUATION KITS**

· HMC680LP4 Evaluation Board

### **DOCUMENTATION**

#### **Data Sheet**

· HMC680 Data Sheet

### REFERENCE MATERIALS -

#### **Quality Documentation**

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Semiconductor Qualification Test Report: BiCMOS-A (QTR: 2013-00235)

## DESIGN RESOURCES 🖵

- HMC680 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

#### **DISCUSSIONS**

View all HMC680 EngineerZone Discussions.

### SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

### **TECHNICAL SUPPORT**

Submit a technical question or find your regional support number.

#### DOCUMENT FEEDBACK 🖳

Submit feedback for this data sheet.

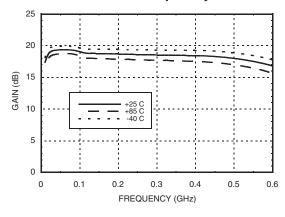
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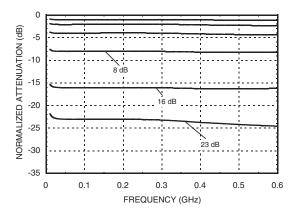
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#### Maximum Gain vs. Frequency



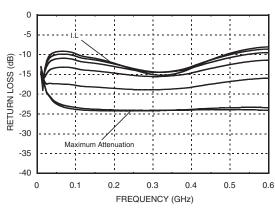
#### Normalized Attenuation

(Only Major States are Shown)



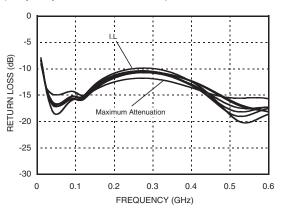
#### **Input Return Loss**

(Only Major States are Shown)



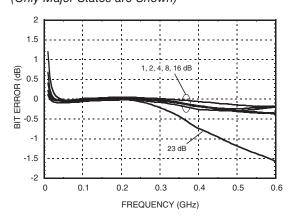
#### **Output Return Loss**

(Only Major States are Shown)

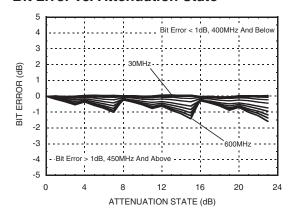


#### Bit Error vs. Frequency

(Only Major States are Shown)



#### Bit Error vs. Attenuation State

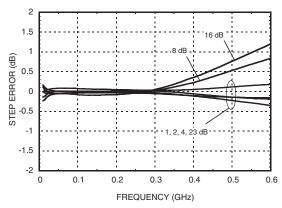






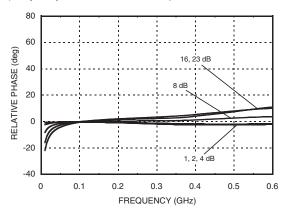
# BICMOS MMIC 5-BIT DIGITAL VARIABLE GAIN AMPLIFIER, 30 - 400 MHz

#### Step Accuracy vs. Frequency



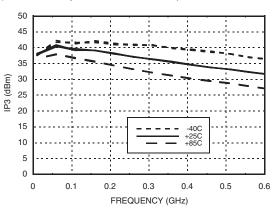
#### Relative Phase vs. Frequency

(Only Major States are Shown)

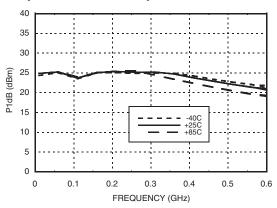


#### Output IP3 vs. Temperature

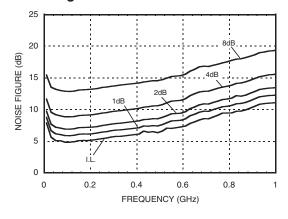
(+5 dBm Output Power Per Tone)



#### Output P1dB vs. Temperature

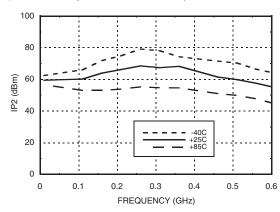


#### Noise Figure vs. Attenuation State



#### Output IP2 vs. Temperature

(+5 dBm Output Power Per Tone)

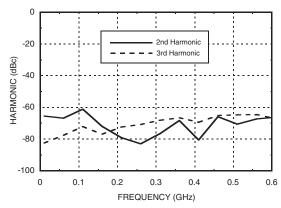






# BICMOS MMIC 5-BIT DIGITAL VARIABLE GAIN AMPLIFIER, 30 - 400 MHz

#### Harmonics vs. Frequency



#### **Absolute Maximum Ratings**

RF Input Power	20 dBm
RF Output Power	22 dBm
Digital Inputs (B0-B4, Latch Enable)	-0.5 to Vdd +0.5V
Bias Voltage (Vdd)	5.6 V
Channel Temperature	125 °C
Continuous Pdiss (T = 85 °C) (derate 42 mW/°C above 85 °C)	1.7 W
Thermal Resistance (channel to ground paddle)	24 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

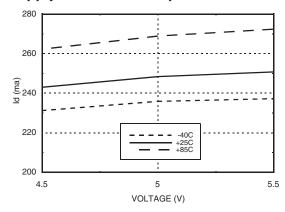
#### **Amp Bias Voltage**

Vdd <sub>RF</sub> (V)	Idd (Typ.) (mA)	
5V	244	

#### **Control Voltage Table**

State	Vdd = +3V	Vdd = +5V
Low	0 to 0.5V @ <1 μA	0 to 0.8V @ <1 μA
High	2 to 3V @ <1 μA	2 to 5V @ <1 μA

#### Supply Current vs. Temperature



#### **Truth Table**

ATTENUATION (dB)	B4 <sup>[1]</sup>	B3 <sup>[1]</sup>	B2	B1	В0
0	0	0	0	0	0
1	0	0	0	0	1
2	0	0	0	1	0
3	0	0	0	1	1
4	0	0	1	0	0
5	0	0	1	0	1
6	0	0	1	1	0
7	0	0	1	1	1
8	0	1	0	0	0
9	0	1	0	0	1
10	0	1	0	1	0
11	0	1	0	1	1
12	0	1	1	0	0
13	0	1	1	0	1
14	0	1	1	1	0
15	0	1	1	1	1
16	1	Х	0	0	0
17	1	Х	0	0	1
18	1	Х	0	1	0
19	1	Х	0	1	1
20	1	Х	1	0	0
21	1	Х	1	0	1
22	1	Х	1	1	0
23	1	Х	1	1	1
[1] Enabling R4 disables R3, the minimum attenuation is 16 dR					

[1] Enabling B4 disables B3, the minimum attenuation is 16 dB

#### **Control Interface:**

The gain of HMC680LP4(E) is controlled by adjusting the state of the attenuator. The attenuator has a 5-bit parallel CMOS/TTL compatible interface. State of the attenuator can be set with respect to the truth table above.

#### Power on sequence:

The ideal power up sequence is: GND, Vdd, Digital inputs, RF inputs. Relative order of the digital inputs is not important as long as they are powered after VDD/GND.

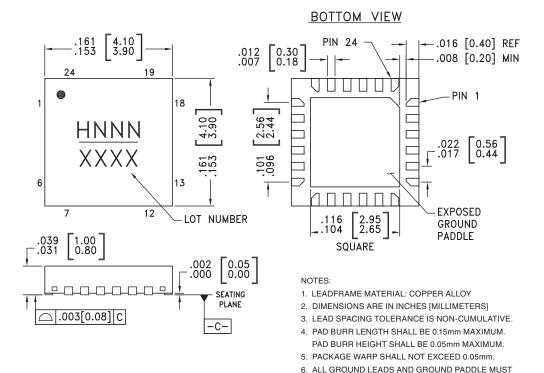




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BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### **Outline Drawing**



#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC680LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H680 XXXX
HMC680LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H680</u> XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260  $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX





# BICMOS MMIC 5-BIT DIGITAL VARIABLE GAIN AMPLIFIER, 30 - 400 MHz

#### **Pin Descriptions**

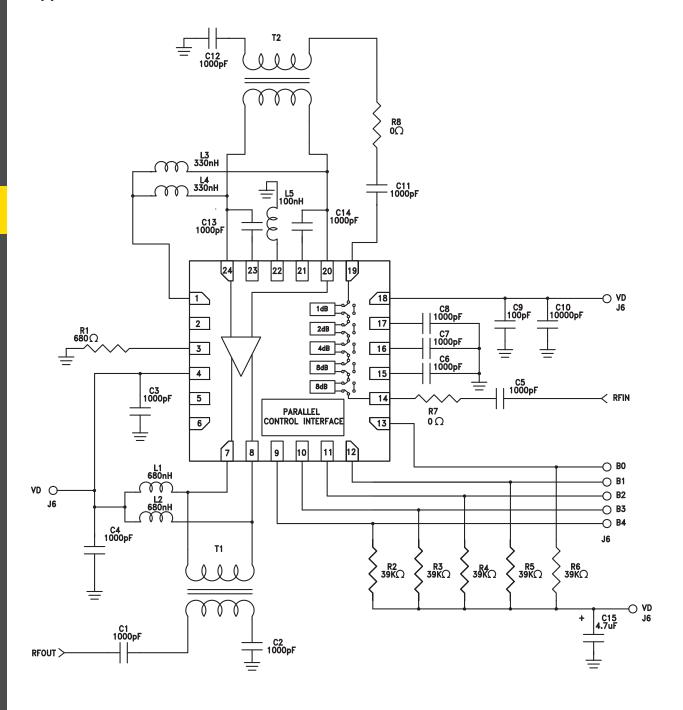
Pin Number	Function	Description	Interface Schematic
1	IBIAS	Bias current to amplifier. External inductors required.	Vdd O Vd O Vdd O V
2, 5, 6, Package Bottom	N/C, GND	These pins and package bottom must be connected to RF/DC ground.	= GRND
3	ISET	External bias resistor to adjust the current of the amplifier.	Vdd O Vdd O VSET O
4, 18	Vdd	Power Supply	Vdd O
9, 10, 11, 12, 13	B4 - B0	Control inputs to digital attenuator. See Truth Table & Control Voltage Table.	45
7, 8	RFOUTP, RFOUTN	Balanced amplifier outputs. External components required	. RFOUTP RFOUTN
20, 24	AMPINN, AMPINP	Balanced Amplifier inputs. External components required.	FB1
21, 23	FB2, FB1	Feedback capacitance for the amplifier.	AMPINP AMPINN
22	LE	Common mode emitter inductor. The LE Pin requires high quality (less than 200mOhms resistance) inductor to ground. An inductance of 100nH is recommended.	LE
14	RFIN	RF input to digital attenuator. DC blocking capacitor required.	RFINO
15, 16, 17	FC3 - FC1	External capacitors to ground are required. Place these capacitors close to the package.	Vdd O FC1 = FC2 O FC3
19	ATTNOUT	RF output to digital attenuator. DC blocking capacitor required.	ATTNOUT O





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#### **Application Circuit**

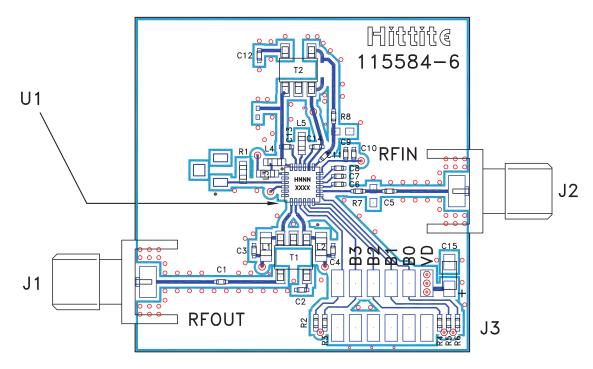






## **BICMOS MMIC 5-BIT DIGITAL VARIABLE GAIN AMPLIFIER, 30 - 400 MHz**

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 115585 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	12 Pin DC Connector
C1 - C8, C11 - C14	1000 pF Capacitor, 0402 Pkg.
C9	100 pF Capacitor, 0402 Pkg.
C10	10k pF Capacitor, 0402 Pkg.
C15	4.7 μF Tantalum Capacitor, Case A Size
L1, L2	680 nH Inductor, 0805 Pkg.
L3, L4	330 nH Inductor, 0603 Pkg.
L5	100 nH Inductor, 0603 Pkg.
R1	680 Ohm Resistor, 0603 Pkg.
R2 - R6	39 kOhm Resistor, 0402 Pkg.
R7, R8	0 Ohm Resistor, 0402 Pkg.
T1, T2	1:1 RF Transformer, MA/COM SMT Balun (ETC1-1-13)
U1	HMC680LP4(E) Variable Gain Amplifier
PCB [2]	115584 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.